

CamSim illumination model

This describes the illumination model (direct and single-bounce indirect) used in CamSim.

It is based on this paper: M. Lambers, S. Hoberg, A. Kolb: Simulation of Time-of-Flight Sensors for Evaluation of Chip Layout Variants. In IEEE Sensors Journal, 15(7), 2015, pages 4019-4026.

The extension for single-bounce indirect illumination is loosely based on this paper: D. Bulczak, M. Lambers, A. Kolb: Quantified, Interactive Simulation of AMCW ToF Camera Including Multipath Effects. In MDPI Sensors, 18(1), 2018, pages 1424-8220.

1 Symbols

1.1 Radiometric

Q : Radiant energy [J]

P : Radiant flux (“power”) [W]

I : Radiant intensity [W/sr]

L : Radiance (“radiant flux per unit solid angle per unit projected area”) [$W/sr/m^2$]

E : Irradiance [W/m^2]

1.2 Geometric

L : Light source position

C : Camera center position

P : Point on object surface seen by camera pixel

\widehat{n}_P : Surface normal at P

$\theta_{P \rightarrow L}$: Angle between \widehat{n}_P and $\widehat{L-P}$

Q : Another point (on another surface) that may act as a virtual point light

\widehat{n}_Q : Surface normal at Q

$\theta_{Q \rightarrow L}$: Angle between \widehat{n}_Q and $\widehat{L-Q}$

1.3 Other

$f_P(\widehat{L-P}, \widehat{n}_P, \widehat{C-P})$: BRDF for $L \rightarrow P \rightarrow C$

$f_Q(\widehat{L-Q}, \widehat{n}_Q, \widehat{P-Q})$: BRDF for $L \rightarrow Q \rightarrow P$

2 Direct Illumination

$I_{L \rightarrow P} = \frac{P_L}{4\pi}$ (if L is point light; there are alternatives)

$L_{L \rightarrow P} = \frac{I_{L \rightarrow P}}{d_{L \rightarrow P}^2}$

$$L_{P \rightarrow C} = f_P(\widehat{L-P}, \widehat{n}_P, \widehat{C-P}) L_{L \rightarrow P} \cos(\theta_{P \rightarrow L})$$

$$E_C = L_{P \rightarrow C} \quad (\text{Note: no factor } \cos(\theta_{C \rightarrow P}) \text{ here})$$

$$P_C = E_C \cdot \text{SensorPixelArea}$$

$$Q_C = P_C \cdot \text{SignalDutyCycle} \cdot \text{ExposureTime}$$

3 Indirect Illumination via Virtual Point Lights

Start with the Rendering Equation:

$$L_{P \rightarrow C} = \int_{\Omega} f_P(\omega_i, \widehat{n}_P, \widehat{C-P}) L_{i \rightarrow P} \cos(\theta_i) d\omega_i$$

Approximate this by splitting into direct and indirect parts, and approximating the indirect part with single-bounce RSM VPLs:

$$L_{P \rightarrow C} = f_P(\widehat{L-P}, \widehat{n}_P, \widehat{C-P}) L_{L \rightarrow P} \cos(\theta_{P \rightarrow L}) + \frac{1}{|\text{RSM}|} \sum_{Q \in \text{RSM}} f_P(\widehat{Q-P}, \widehat{n}_P, \widehat{C-P}) L_{Q \rightarrow P} \cos(\theta_{P \rightarrow Q})$$

The direct part is already computed in the direct step as $L_{P \rightarrow C}$. Add the indirect part to it:

$$L_{P \rightarrow C}^* = L_{P \rightarrow C} + \frac{1}{|\text{RSM}|} \sum_{Q \in \text{RSM}} f_P(\widehat{Q-P}, \widehat{n}_P, \widehat{C-P}) L_{Q \rightarrow P} \cos(\theta_{P \rightarrow Q})$$

using $L_{Q \rightarrow P} = f_Q(\widehat{L-Q}, \widehat{n}_Q, \widehat{P-Q}) L_{L \rightarrow Q} \cos(\theta_{Q \rightarrow L})$

and $L_{L \rightarrow Q} = \frac{I_{L \rightarrow Q}}{d_{L \rightarrow Q}^2}$, $I_{L \rightarrow Q} = \frac{P_L}{4\pi}$

4 Values to Store in RSM

- Parameters that allow BRDF sampling at Q , e.g. k_d, k_s, s for modified Phong
- Position of Q (to perform shadow test and to compute $\widehat{Q-P}, \theta_{P \rightarrow Q}, \widehat{L-Q}, \widehat{P-Q}, \theta_{Q \rightarrow L}$)
- \widehat{n}_Q
- $L_{L \rightarrow Q}$